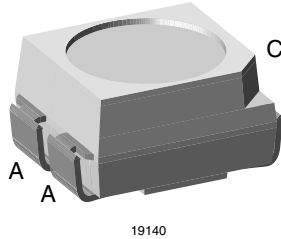


## Bicolor SMD LED PLCC-3



### DESCRIPTION

These devices have been designed to meet the increasing demand for surface mounting technology.

The package of the TLMEK3100 is the PLCC-3 (equivalent to a size B tantalum capacitor).

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

This SMD device consists of a red and yellow chip. So it is possible to choose the color in one device.

### PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-3
- Product series: bicolor
- Angle of half intensity:  $\pm 60^\circ$

### FEATURES

- SMD LED with exceptional brightness
- Multicolored
- Luminous intensity categorized
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with infrared, vapor phase and wave solder processes according to CECC
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit  $I_{Vmax}/I_{Vmin} \leq 2.0$
- Lead (Pb)-free device



### APPLICATIONS

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols

### PARTS TABLE

PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
TLMEK3100-GS08	Red/yellow	AllnGaP on GaAs
TLMEK3100-GS18	Red/yellow	AllnGaP on GaAs



<b>ABSOLUTE MAXIMUM RATINGS<sup>1)</sup></b>				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage per diode	$I_R = 10 \mu\text{A}$	$V_R$	6	V
DC Forward current per diode	$T_{\text{amb}} \leq 85 \text{ }^\circ\text{C}$	$I_F$	30	mA
Surge forward current per diode	$t_p \leq 10 \mu\text{s}$	$I_{\text{FSM}}$	0.5	A
Power dissipation per diode	$T_{\text{amb}} \leq 85 \text{ }^\circ\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	125	$^\circ\text{C}$
Operating temperature range		$T_{\text{amb}}$	- 40 to + 100	$^\circ\text{C}$
Storage temperature range		$T_{\text{stg}}$	- 55 to + 100	$^\circ\text{C}$
Soldering temperature	$t \leq 5 \text{ s}$	$T_{\text{sd}}$	260	$^\circ\text{C}$
Thermal resistance junction/ambient	mounted on PC board (pad size > 16 mm <sup>2</sup> )	$R_{\text{thJA}}$	400	K/W

Note:

<sup>1)</sup>  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> RED</b>						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity	$I_F = 20 \text{ mA}$	$I_V$	40		125	mcd
Dominant wavelength	$I_F = 20 \text{ mA}$	$\lambda_d$		630		nm
Peak wavelength	$I_F = 20 \text{ mA}$	$\lambda_p$		643		nm
Angle of half intensity	$I_F = 20 \text{ mA}$	$\phi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$	$V_F$		1.9	2.6	V
Reverse voltage	$I_R = 10 \mu\text{A}$	$V_R$	5			V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

<b>OPTICAL AND ELECTRICAL CHARACTERISTICS<sup>1)</sup> YELLOW</b>						
PARAMETER	TEST CONDITION	SYMBOL	MIN	TYP.	MAX	UNIT
Luminous intensity	$I_F = 20 \text{ mA}$	$I_V$	40		200	mcd
Dominant wavelength	$I_F = 20 \text{ mA}$	$\lambda_d$	581	588	594	nm
Peak wavelength	$I_F = 20 \text{ mA}$	$\lambda_p$		590		nm
Angle of half intensity	$I_F = 20 \text{ mA}$	$\phi$		$\pm 60$		deg
Forward voltage	$I_F = 20 \text{ mA}$	$V_F$		2.0	2.6	V
Reverse voltage	$I_R = 10 \mu\text{A}$	$V_R$	5			V
Junction capacitance	$V_R = 0, f = 1 \text{ MHz}$	$C_j$		15		pF

Note:

<sup>1)</sup>  $T_{\text{amb}} = 25 \text{ }^\circ\text{C}$ , unless otherwise specified

**TYPICAL CHARACTERISTICS**

$T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified

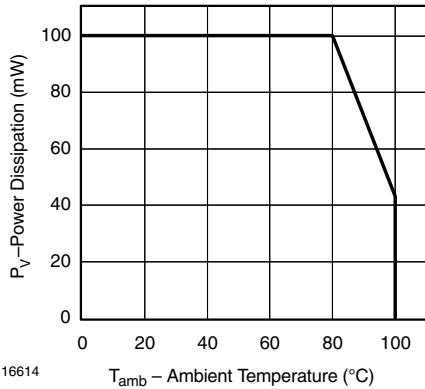


Figure 1. Power Dissipation vs. Ambient Temperature

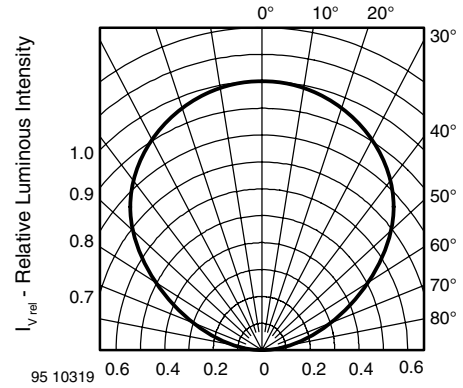


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

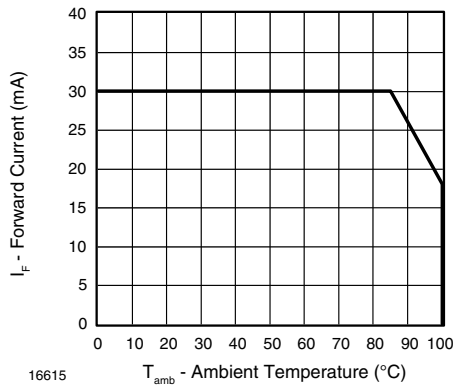


Figure 2. Forward Current vs. Ambient Temperature for InGaN

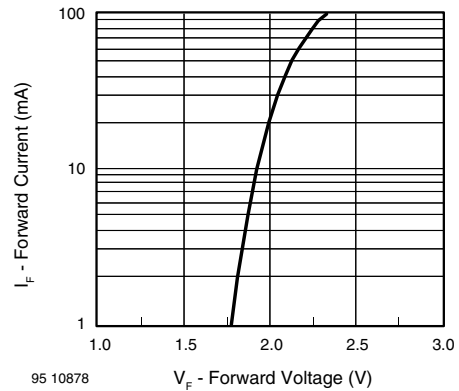


Figure 5. Forward Current vs. Forward Voltage

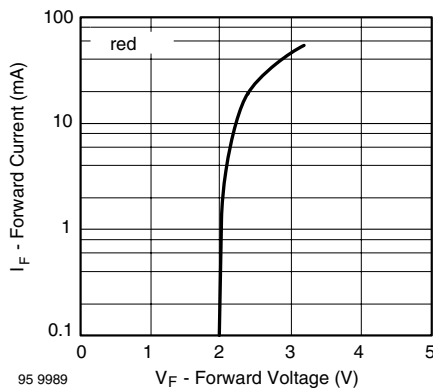


Figure 3. Pulse Forward Current vs. Pulse Duration

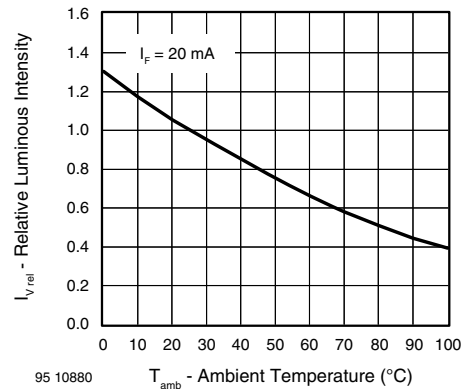


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

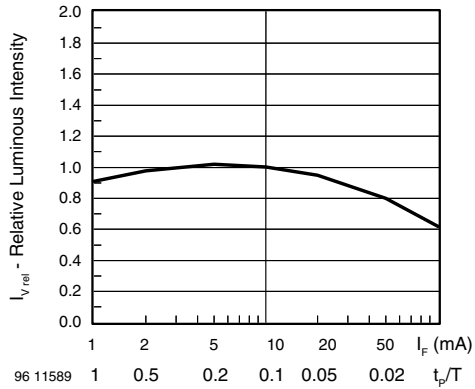


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

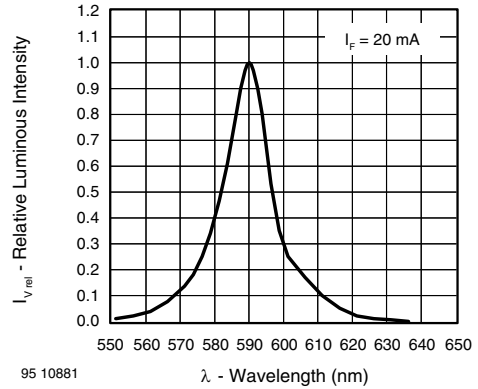


Figure 10. Relative Intensity vs. Wavelength

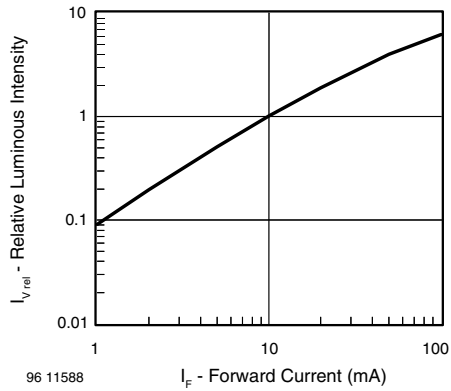


Figure 8. Relative Luminous Intensity vs. Forward Current

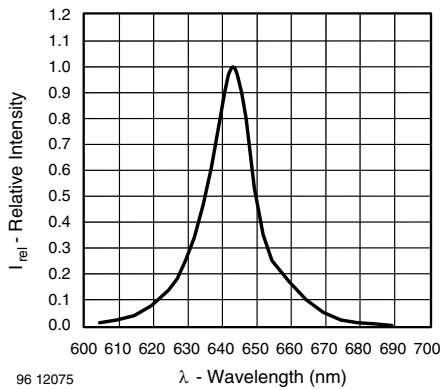
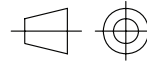
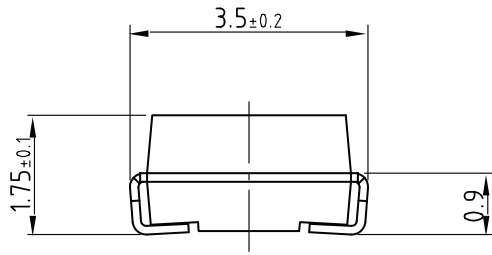
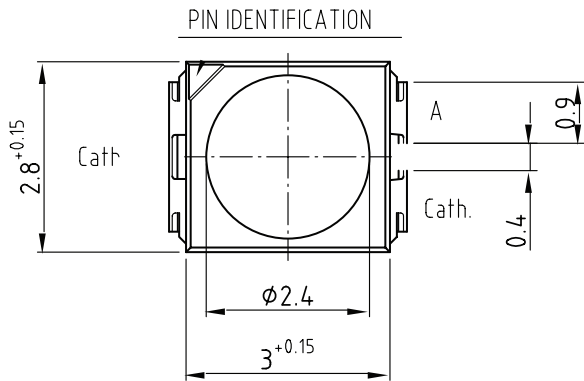


Figure 9. Relative Intensity vs. Wavelength

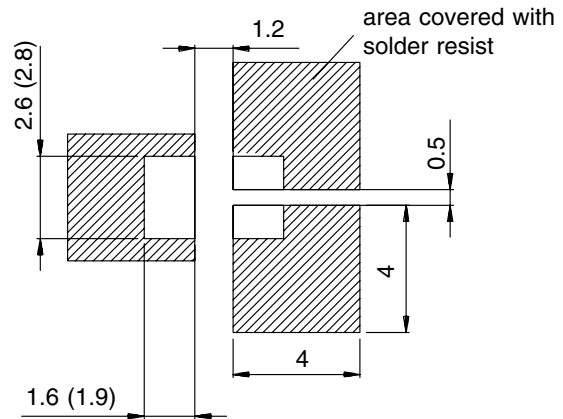
**PACKAGE DIMENSIONS** in millimeters



technical drawings  
according to DIN  
specifications



**Mounting Pad Layout**



Dimensions: IR and Vaporphase  
(Wave Soldering)

Drawing-No. : 6.541-5054.01-4  
Issue: 2; 02.12.05  
16276\_1

## Vishay Semiconductors

### Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design  
and may do so without further notice.

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